

SEMITRANS[®] 3

Trench IGBT Modules

SKM 300GB066D

Features

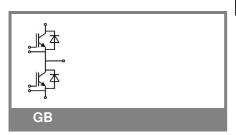
- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability, self limiting to 6 x I_C

Typical Applications*

- AC inverter drives
- UPS
- Electronic welders

Remarks

- Case temperature limited to T_c = 125°C max, recommended T_{op} = -40 ... +150°C
- Product reliability results are valid for T_i ≤150°C
- Short circuit data: $t_p \le 6$ s; $V_{GE} \le 15V$; $T_j = 150^{\circ}C$; $V_{cc} \le 360V$, use of soft R_G necessary!
- Take care of over-voltage caused by stray inductances



Absolute	Absolute Maximum Ratings $T_{case} = 25^{\circ}C$, unless otherwise specified				
Symbol	Conditions		Values	Units	
IGBT	•				
V_{CES}	T _j = 25 °C		600	V	
I _C	T _j = 175 °C	T _c = 25 °C	390	Α	
		$T_c = 80 ^{\circ}C$	300	Α	
I _{CRM}	I _{CRM} =2xI _{Cnom}		600	Α	
V_{GES}			± 20	V	
t _{psc}	V_{CC} = 360 V; $V_{GE} \le 15$ V; VCES < 600 V	T _j = 150 °C	6	S	
Inverse D	iode				
I_{F}	T _j = 175 °C	$T_c = 25 ^{\circ}C$	350	Α	
		$T_c = 80 ^{\circ}C$	250	Α	
I _{FRM}	I _{FRM} =2xI _{Fnom}		600	Α	
I _{FSM}	t _p = 10 ms; sin.	T _j = 175 °C	1760	Α	
Module					
$I_{t(RMS)}$			500	Α	
T_{vj}			- 40 + 175	°C	
T _{stg}			- 40 + 125	°C	
V _{isol}	AC, 1 min.		4000	V	

Characteristics T _{case} = 25°			: 25°C, ur	5°C, unless otherwise specified		
Symbol	Conditions		min.	typ.	max.	Units
IGBT						•
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 4.8 \text{ mA}$		5	5,8	6,5	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = V_{CES}$	T _j = 25 °C		0,15	0,45	mA
V _{CE0}		T _i = 25 °C		0,9	1	V
		T _j = 150 °C		0,85	0,9	V
r _{CE}	V _{GE} = 15 V	T _j = 25°C		1,8	3	mΩ
		T _j = 150°C		2,7	3,8	mΩ
V _{CE(sat)}	I _{Cnom} = 300 A, V _{GE} = 15 V	T _j = 25°C _{chiplev.}		1,45	1,9	V
, ,		T _j = 150°C _{chiplev} .		1,7	2,1	V
C _{ies}				18,5		nF
C _{oes}	$V_{CE} = 25, V_{GE} = 0 V$	f = 1 MHz		1,2		nF
C _{res}				0,55		nF
Q_G	V _{GE} = -8V+15V			2400		nC
R _{Gint}	T _j = °C			1		Ω
t _{d(on)}				150		ns
t _r	R_{Gon} = 2,4 Ω	$V_{CC} = 300V$		48		ns
E _{on}		I _C = 300A		7,5		mJ
$t_{d(off)}$	R_{Goff} = 2,4 Ω	T _j = 150 °C		540		ns
t _f		$V_{GE} = -8V/+15V$		53		ns
E_{off}				11,5		mJ
R _{th(j-c)}	per IGBT				0,15	K/W



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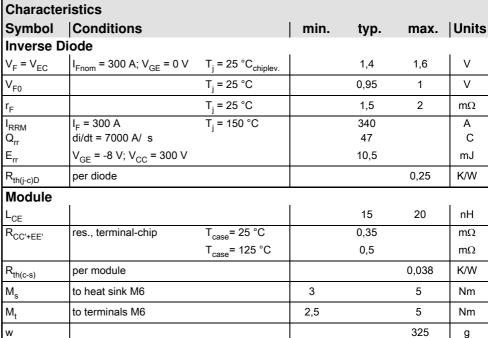
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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.





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L _{th} Symbol	Conditions	Values	Units
Z _{th(i,a)}			
Z _{th(j-c)l}	i = 1	107	mk/W
R _i	i = 2	30	mk/W
R _i	i = 3	11,6	mk/W
R _i	i = 4	1,4	mk/W
tau _i	i = 1	0,054	s
tau _i	i = 2	0,0144	s
taui	i = 3	0,0007	s
tau _i	i = 4	0,0004	s
Z _{th(j-c)D}			<u>.</u>
R _i	i = 1	140	mk/W
R _i	i = 2	82	mk/W
R_i	i = 3	23,5	mk/W
R _i	i = 4	4,5	mk/W
tau _i	i = 1	0,054	s
tau _i	i = 2	0,01	s
taui	i = 3	0,0015	s
tau _i	i = 4	0,0002	s

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